

SEMICONDUCTOR CONDENSED CATALOG SUPPLEMENT

The semiconductor devices listed herein are available through your local Raytheon Franchised Distributor.

With these additional devices, Raytheon now brings you an even more complete selection of semi-conductors.

Silicon and germanium transistors, diodes and rectifiers — chances are you'll find just the right device for your application in the broad Raytheon Semiconductor line. Raytheon Franchised Distributors offer — complete technical service, off-the-shelf delivery and competitive factory prices.

	TO-5 Package	TO-18 Package	Microbloc Package	
	2N497	2N717	RT497(M)	-
	2N498	2N718	RT498(M)	-
	2N656	2N719	RT656(M)	
	2N657	2N720	RT657(M)	
	2N696	2N730	RT696(M)	4
	2N697	2N731	RT697(M)	
	2N698		RT698(M)	i
	2N699		RT699(M)	
NPN	2N1409		RT717(M)	
NEN-	2N1410		RT718(M)	
	2N1420		RT719(M)	
	2N1507		RT720(M) RT730(M)	
Silicon	2N2008 (RT5202)		RT731(M)	-
Officon			RT1409(M)	-
			RT1410(M)	
			RT1420(M)	1
Mesa				500
		• INDUSTRIAL TYPE (TO-5)		
Tuanalatana	2N1983	2N1988	RT484	
Transistors	2N1984	2N1989 2N1990	RT5151 RT5152	
	2N1985 2N1986	RT482	RT5203	
	2N1987	RT483	RT5204	
			RT5212	
	HIGH GAIN, HIGH CURRENT (TO-5)			-
	RT5401	RT5402	RT5404	1
	K13401	RT5403		
	• LOW NOISE (TO-5)			
		RT5230		
NPN Silicon		GH CURRENT, FAST SWITC		
Planar Transistara	TO-5 Package	TO-18 Package	Microbloc Package	
Planar Transistors	2N1613	2N718A	RT718A(M)	
A SHARE WAS A STATE OF THE STAT	2N1893	2N720A	RT1613(M)	



DISTRIBUTOR PRODUCTS DIVISION

Westwood, Massachusetts

			And the second of the		
		SPECIAL DIODES (Case A)			RAYTHEON
		Universal General Purpose	Low Leakage	600 Volt Switching	ALIE CONTRACTOR OF THE PARTY OF
		RD250	RD1356 RD1357	RD500	
			RD1358 RD1359		
		HIGH CONDUCT BACK			
	0.11.	1N625, 1N625A 1N626	1N793 1N794	1N839 1N840	
	Silicon Diodes	1N627	1N795	1N841	CACE A
		1N628, 1N628A 1N629	1N796 1N797	1N842 1N843	CASE A
		1N643, 1N643A	1N798	1N844	CATHODE
		1N658, 1N658A 1N659, 1N659A	1N799 1N800	1N845 1N890	TERMINAL
		1N660, 1N660A 1N661, 1N661A	1N801 1N802	1N891 1N892	0.107"
		1N662, 1N662A	1N803	1N893	max. dia.
		1N663, 1N663A 1N778	1N804 1N806	1N934 RD669*	
		1N779	1N807	RD2121	
		1N789 1N790	1N808 1N809	RD2122 RD2123	0.265" max.
		1N791 1N792	1N837, 1N837A 1N838	RD2124	R
		*Also available with s	T		
		LOW CONDUCTANCE, VERY FAST (Case A)			0.021 " nin.
		1N251, 1N251A	1	.N252, 1N252A	max. dia.
	Silicon Mesa	VERY HIGH CONDUCT			
	Silicon Nicsa	1N690	1N693	1N922	
	Diodes	1N691 1N692	1N920 1N921	1N923 RD750	
		VERY LOW CAPACITANCE, VERY FAST			CASE B
	Silicon Planar		ECOND (Case B)		CATHODE
		1N903 1N904	1N907 1N908	1N926 1N927	TERMINAL
	Diodes	1N905	1N914, 1N914A	1N928	0.108"
		1N906	1N916, 1N916A 1N925	1N3064	max. dia.
		GENERAL			
		1N676	1N849	1N870	0.310" max.
		1N677 1N678	1N850 1N851	1N871 1N872	R
		1N679	1N852	1N873	
		1N681 1N682	1N853 1N857	1N874 1N875	U
	Silicon Rectifiers	1N683 1N684	1N858 1N859	1N879 1N880	0.021 " min.
	Omoon Rootmoro	1N685	1N860	1N881	max. dia.
		1N686 1N687	1N861 1N862	1N882 1N883	
		1N689	1N863	1N884	
		1N846 1N847	1N864 1N868	1N885 1N886	
		1N848	1N869		
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